74LVC1GU04

Unbuffered inverter Rev. 12 — 9 April 2013

Product data sheet

1. **General description**

The 74LVC1GU04 is a single unbuffered inverter.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

Features and benefits 2.

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- \pm 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Input accepts voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Ordering information 3.

Table 1. **Ordering information**

Type number	Package							
	Temperature range Name		Description	Version				
74LVC1GU04GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74LVC1GU04GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74LVC1GU04GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74LVC1GU04GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74LVC1GU04GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1GU04GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm	SOT1202				
74LVC1GU04GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				



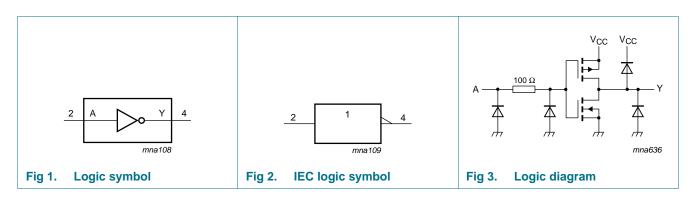
4. Marking

Table 2. Marking codes

Type number	Marking[1]
74LVC1GU04GW	VD
74LVC1GU04GV	VU4
74LVC1GU04GM	VD
74LVC1GU04GF	VD
74LVC1GU04GN	VD
74LVC1GU04GS	VD
74LVC1GU04GX	VD

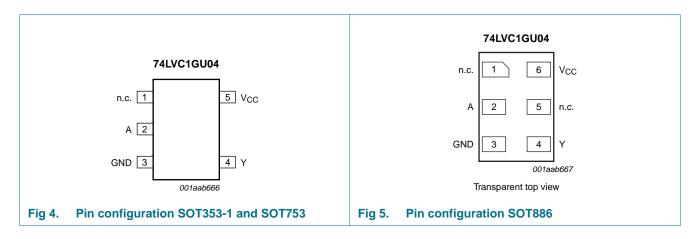
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

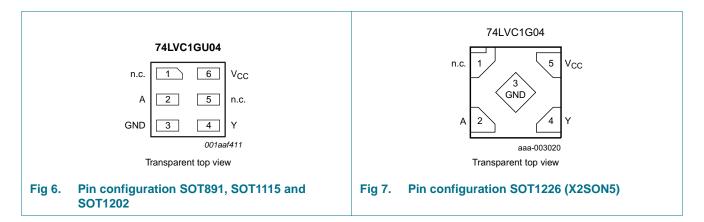
5. Functional diagram



6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	TSSOP5 and X2SON5	XSON6	
n.c.	1	1	not connected
Α	2	2	data input
GND	3	3	ground (0 V)
Υ	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

7. Functional description

Table 4. Function table [1]

Input (A)	Output (Y)
L	Н
Н	L

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-	-50	mA
VI	input voltage		<u>[1]</u> -0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
Vo	output voltage	Active mode	[<u>1][2]</u> -0.5	$V_{CC} + 0.5$	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I _{CC}	supply current		-	+100	mA
I_{GND}	ground current		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	<u>[3]</u> _	250	mW
T _{stg}	storage temperature		-65	+150	°C

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	0	-	20	ns/V
		V _{CC} = 2.7 V to 5.5 V	0	-	10	ns/V

^[2] When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

^[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V_{IH}	HIGH-level input voltage	$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 5.5 V	-	-	$0.25 \times V_{CC}$	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V _{CC} - 0.1	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	V
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	V
		$I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	V
II	input leakage current	$V_I = 5.5 \text{ V or GND}$; $V_{CC} = 0 \text{ V to}$ 5.5 V	-	±0.1	±5	μΑ
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	0.1	10	μΑ
C _I	input capacitance	V_{CC} = 3.3 V; V_I = GND to V_{CC}	-	6	-	pF
T _{amb} = -	40 °C to +125 °C					
V_{IH}	HIGH-level input voltage	$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	$0.8 \times V_{CC}$	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	$0.2 \times V_{CC}$	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V _{CC} – 0.1	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	0.95	-	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.7	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	1.9	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.0	-	-	V
		$I_O = -32$ mA; $V_{CC} = 4.5$ V	3.4	-	-	V

Table 7. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.7	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.80	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.80	V
Iį	input leakage current	$V_1 = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to} $ 5.5 V	-	±0.1	±5	μА
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	200	μΑ

^[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		–40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	A to Y; see Figure 8	[2]						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		0.3	1.7	5.0	0.3	6.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.3	1.3	4.0	0.3	5.5	ns
		$V_{CC} = 2.7 \text{ V}$		0.5	1.7	5.0	0.5	6.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		0.5	1.6	3.7	0.5	5.0	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.5	1.3	3.0	0.5	4.0	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 3.3 \text{ V}$	[3]	-	14.9	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

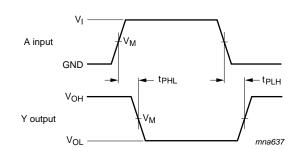
N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

12. Waveforms



Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig 8. The input A to output Y propagation delay times

Table 9. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
1.65 V to 1.95 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3 V to 2.7 V	$0.5 \times V_{CC}$	0.5 × V _{CC}
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5 \times V_{CC}$	0.5 × V _{CC}

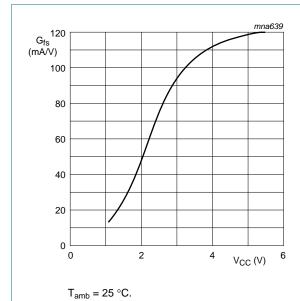
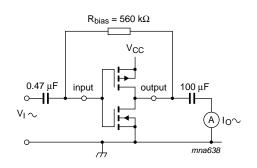


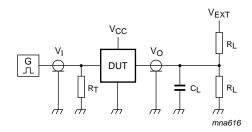
Fig 9. Typical forward transconductance as a function of supply voltage



$$G_{fs} = \frac{\Delta I_O}{\Delta V_I}$$

f_i = 1 kHz at V_O is constant

Fig 10. Test set-up for measuring forward transconductance



Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 11. Test circuit for measuring switching times

Table 10. Test data

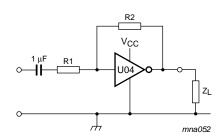
Supply voltage	Input		Load	Load		
V _{CC}	VI	$t_r = t_f$	CL	R_L	t _{PLH} , t _{PHL}	
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open	
2.3 V to 2.7 V	V_{CC}	\leq 2.0 ns	30 pF	500 Ω	open	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	

13. Application information

Some applications are:

- Linear amplifier (see Figure 12)
- In crystal oscillator design (see Figure 13)

Remark: All values given are typical unless otherwise specified.



 $V_{o(p-p)} = V_{CC} - 1.5 \text{ V}$ centered at $0.5V_{CC}$.

$$A_u = -\frac{G_{OL}}{1 + \frac{Rl}{R2}(1 + G_{OL})} \label{eq:au}$$

 G_{OL} = loop gain.

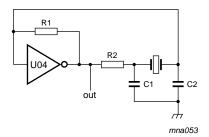
 A_u = voltage amplification.

 $R1 \ge 3 \text{ k}\Omega, R2 \le 1 \text{ M}\Omega$

 $Z_L > 10 \text{ k}\Omega; A_{OL} = 20 \text{ (typ.)}$

Typical unity gain bandwidth product is 5 MHz.

Fig 12. Used as a linear amplifier



C1 = 47 pF (typ.)

C2 = 22 pF (typ.)

R1 = 1 M Ω to 10 M Ω (typ.)

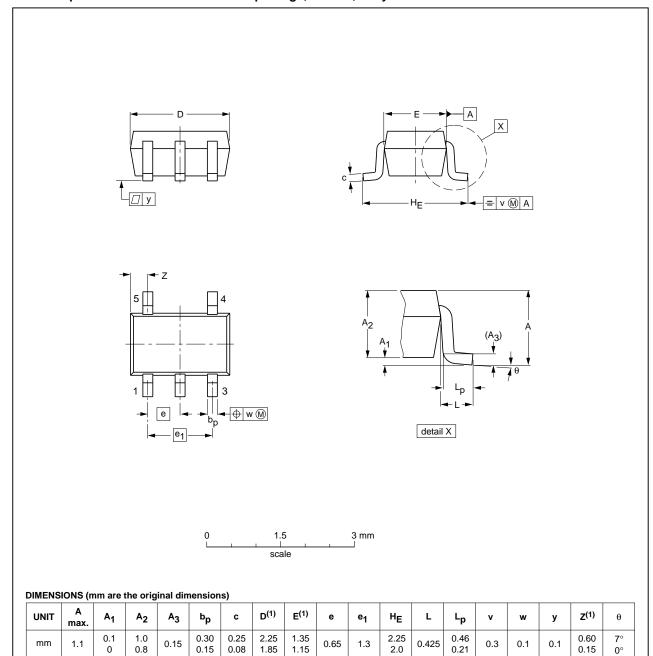
R2 optimum value depends on the frequency and required stability against changes in V_{CC} or average minimum I_{CC} (I_{CC} is typically 2 mA at V_{CC} = 3.3 V and f = 10 MHz).

Fig 13. Crystal oscillator configuration

14. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



. . .

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

	OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
;	SOT353-1		MO-203	SC-88A			-00-09-01- 03-02-19

Fig 14. Package outline SOT353-1 (TSSOP5)

74LVC1GU04

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Plastic surface-mounted package; 5 leads

SOT753

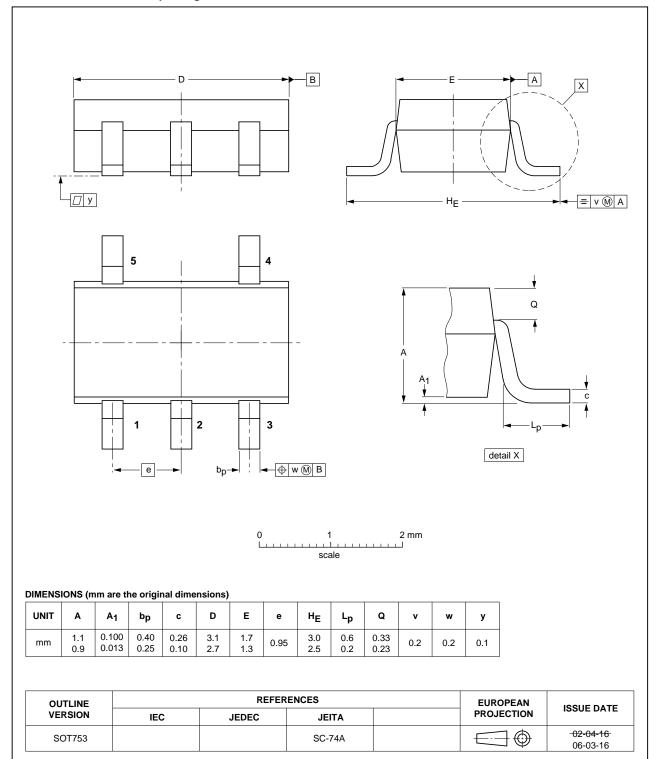


Fig 15. Package outline SOT753 (SC-74A)

74LVC1GU04

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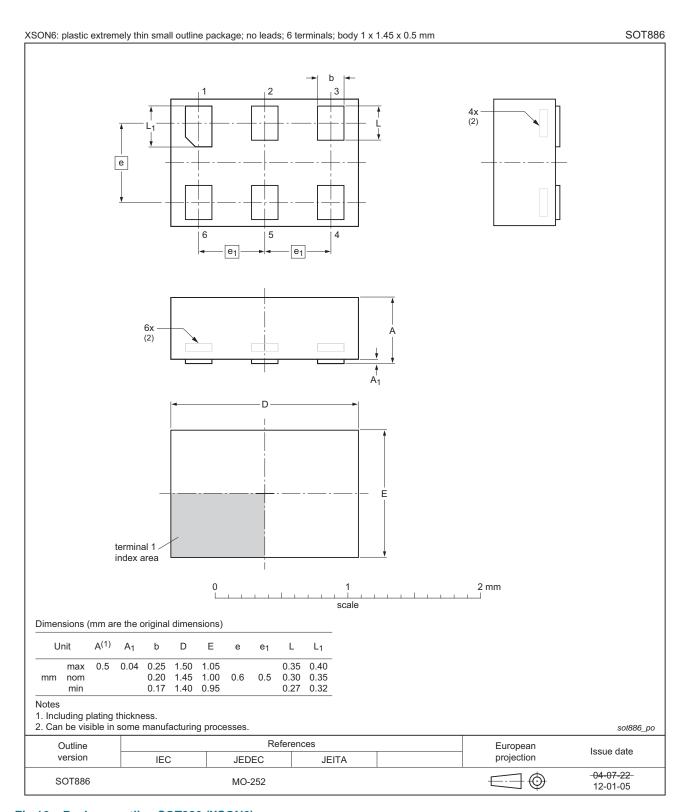


Fig 16. Package outline SOT886 (XSON6)

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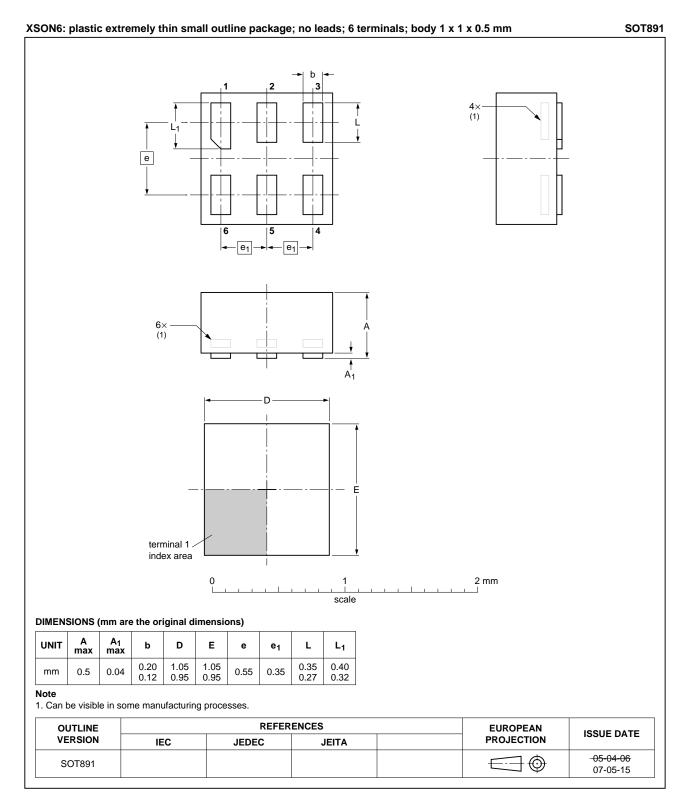


Fig 17. Package outline SOT891 (XSON6)

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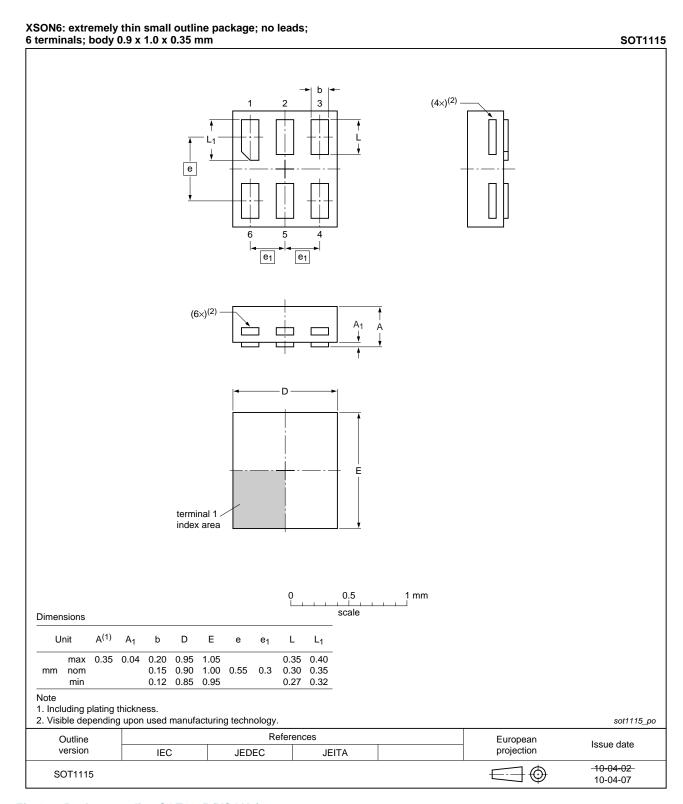


Fig 18. Package outline SOT1115 (XSON6)

74LVC1GU04

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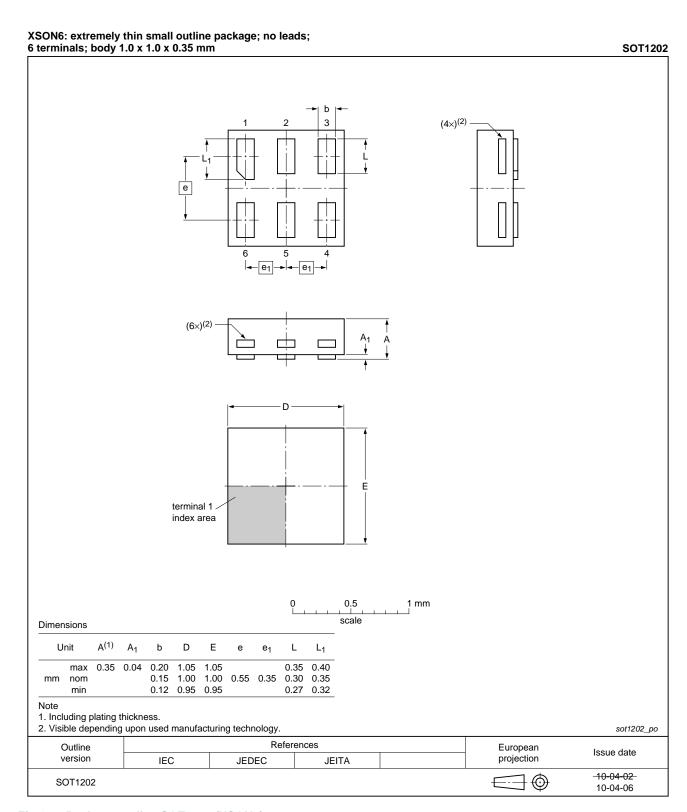


Fig 19. Package outline SOT1202 (XSON6)

74LVC1GU04

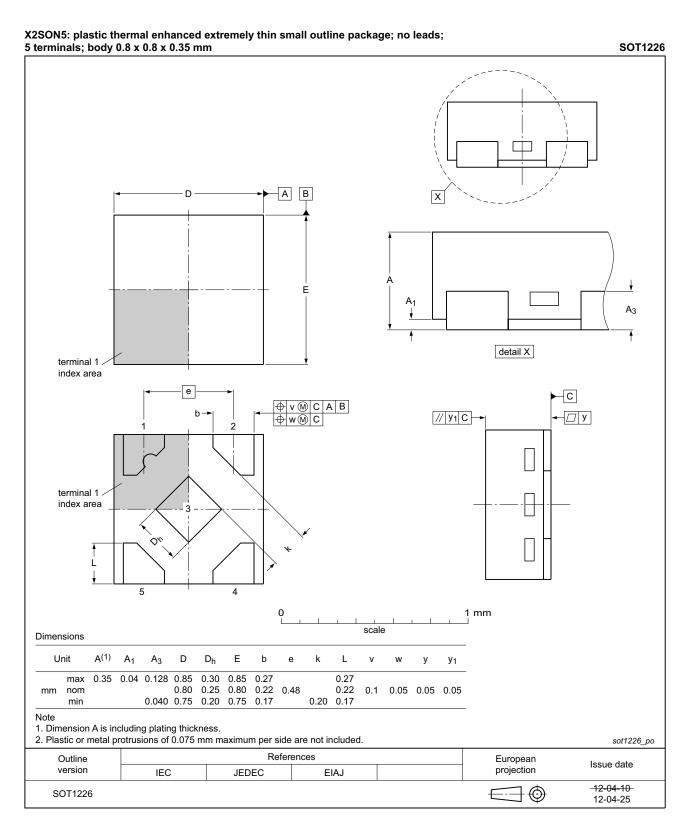


Fig 20. Package outline SOT1226 (X2SON5)

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15. Abbreviations

Table 11. Abbreviations

Acronym	Description	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	

16. Revision history

Table 12. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1GU04 v.12	20130409	Product data sheet	-	74LVC1GU04 v.11
Modifications:	Descriptive title changed to Unbuffered inverter.			
74LVC1GU04 v.11	20120702	Product data sheet	-	74LVC1GU04 v.10
Modifications:	 Added type nu 	mber 74LVC1GU04GX (SOT122	26)	
	 Package outling 	e drawing of SOT886 (Figure 16) modified.	
74LVC1GU04 v.10	20111201	Product data sheet	-	74LVC1GU04 v.9
Modifications:	 Legal pages up 	odated.		
74LVC1GU04 v.9	20101021	Product data sheet	-	74LVC1GU04 v.8
74LVC1GU04 v.8	20070612	Product data sheet	-	74LVC1GU04 v.7
74LVC1GU04 v.7	20061006	Product data sheet	-	74LVC1GU04 v.6
74LVC1GU04 v.6	20040921	Product specification	-	74LVC1GU04 v.5
74LVC1GU04 v.5	20040628	Product specification	-	74LVC1GU04 v.4
74LVC1GU04 v.4	20030630	Product specification	-	74LVC1GU04 v.3
74LVC1GU04 v.3	20030212	Product specification	-	74LVC1GU04 v.2
74LVC1GU04 v.2	20010406	Product specification	-	74LVC1GU04 v.1
74LVC1GU04 v.1	20001212	Product specification	-	-

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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